Wideband Quad 2:1 Video Switch

The NCS6433 is a wide bandwidth, bidirectional, Quad 2:1, NMOS-based video switch suitable for dealing with video signals such as RGB, composite, S-Video, and component video (YPbPr).

The NCS6433 is controlled by a single switch–enabled (\overline{OE}) input. When \overline{OE} is low the switch is enabled and the A port is connected to the B port. When \overline{OE} is high the switch is disabled and the high–impedance state exists between the A and B ports. The line select (SEL) input controls the data path of the multiplexer/demultiplexer.

The NCS6433 has a wide bandwidth, low crosstalk, low on resistance, and fast switching times making it suitable for high-frequency video applications in high definition LCD TV's.

Features

- Very Wide Frequency Bandwidth: 570 MHz
- Low Switch Serial Resistance R_{DS(on)}, 4 Ω Typical
- Power Supply Voltage, 5 V
- Less Than 0.25 ns Bidirectional Maximum Propagation Delay Through Switch
- Low Quiescent Current: 3 µA Maximum
- Very Low Crosstalk, -80 dB Typical at 10 MHz
- Control Inputs are TTL/CMOS Compatible
- Ideal for High Definition Video Applications
- ESD HBM Protection 8 kV
- Fast Switching Better Than 10 ns
- Capable of Driving a High Current at the Output (>100 mA)
- Available in SOIC-16 or TSSOP-16 Package
- This is a Pb–Free Device

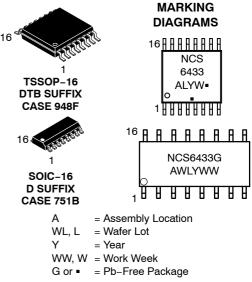
Typical Applications

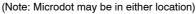
- Flat Panel Displays including LCDTV
- CRT Displays
- DVD Reader/Writer
- Set-Top Boxes

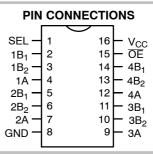


ON Semiconductor®

http://onsemi.com







TRUTH TABLE

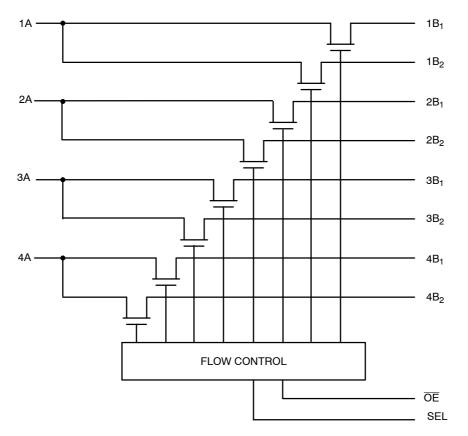
SEL	ŌE	Function
X	H	Open
L	L	A = B ₁
H	L	A = B ₂

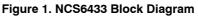
PIN NAMES

Pin	Description
ŌĒ	Bus Switch Enables
SEL	Select Inputs
А	Bus A
B ₁ , B ₂	Bus B

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.





ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
NCS6433DR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
NCS6433DTBR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ATTRIBUTES

Characteristics		Value
ESD Protection Human Body Model, R = 1000 Ω , C = 100 pF (Note 1) Machine Model	F I/O Pins 2–7, 9–14 All Pins All Pins	8 kV 2 kV 100 V
Flammability Rating	Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in.
Meets or exceeds JEDEC Spec EIA/JESD78	3 IC Latch-up Test	

1. Meets or exceeds JEDEC spec JESD22-A114-B.

2. For additional information, see Application Note AND8003/D

MAXIMUM RATINGS

Parameter			Value	Unit
DC Supply Voltage		V _{CC}	-0.5 to +5.5	V
DC Input Voltage		VI	-0.5 to +5.5	V
DC Output Voltage		Vo	-0.5 to +5.5	V
DC Input Diode Current		Ι _{ΙΚ}	- 50	mA
DC Output Diode Current		I _{OK}	- 50	mA
DC Output Sink Current		Ι _Ο	128	mA
DC Supply Current per Supply Pin		I _{CC}	±100	mA
DC Ground Current per Ground Pin		I _{GND}	±100	mA
Storage Temperature Range		T _{STG}	-65 to +150	°C
Lead Temperature, 1 mm from Case for 10 Seconds		ΤL	260	°C
Junction Temperature Under Bias (Note 3)		TJ	+150	°C
Thermal Resistance	SOIC-16 TSSOP-16	θ_{JA}	125 170	°C/W

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

3. Maximum electrical ratings are defined as those values beyond which damage to the device may occur at $T_A = +25^{\circ}C$.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Min	Max	Unit
V _{CC}	Supply Voltage	Operating, Data Retention Only	4.75	5.25	V
VI	Input Voltage	(Note 4)	0	5.25	V
Vo	Output Voltage	(HIGH or LOW State)	0	5.25	V
T _A	Operating Free-Air Temperature		-40	+85	°C
$\Delta t/\Delta V$	Input Transition Rise or Fall Rate Switch I/O	Switch Control Input V _{CC} = 5.0 V \pm 0.5 V	0	DC 5	ns/V

4. Unused control inputs may not be left open. All control inputs must be tied to a high or low logic input voltage level.

Symbol	Parameter	Conditions	V _{CC} (V)	Min	Тур*	Max	Unit
V _{IK}	Clamp Diode Voltage	I _{IN} = -18 mA	4.5	-1.2	-0.8		V
V _{IH}	High-Level Input Voltage		4.0 to 5.5	2.0			V
V _{IL}	Low-Level Input Voltage		4.0 to 5.5			0.8	V
ILI	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	5.5			±1.0	μA
I _{OZ}	Off-State Leakage Current	$0 \le A, B \le V_{CC}$	5.5			±1.0	μΑ
R _{ON}	Switch On Resistance (Note 5)	V_{IN} = 1 V, I_{ON} = 13 mA, R_{L} = 75 Ω	4.5		4.0	7.0	Ω
		V_{IN} = 2 V, I_{ON} = 26 mA, R_{L} = 75 Ω	4.5		7.0	10	
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND, $I_{OUT} = 0$	5.5			3.0	μA
ΔI_{CC}	Increase In I _{CC} per Input	One input at 3.4 V, Other inputs at V_{CC} or GND	5.5			2.5	mA

*Typical values are at V_{CC} = 5.0 V and T_A = 25°C.
5. Measured by the voltage drop between A and B pins at the indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

AC ELECTRICAL CHARACTERISTICS (T_A = -40°C to +85°C, C_L = 20 pF, RU = RD = 75 Ω unless otherwise specified) (Note 6)

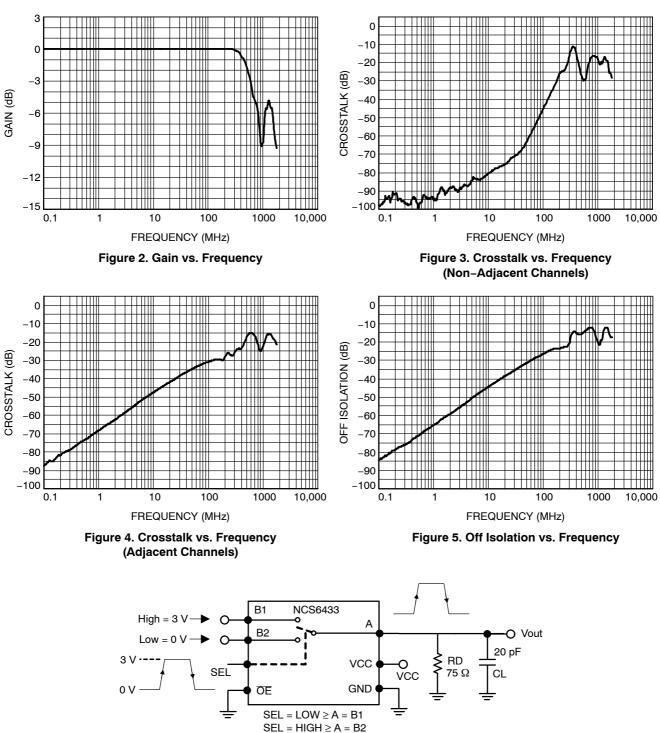
				V _{CC} = 4.5–5.5 V		
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
t _{ON}	Turn On Time	R_L = 75 Ω, C_L = 20 pF, see Figure 7		2.8	5.0	ns
tOFF	Turn Off Time	R_L = 75 Ω, C_L = 20 pF, see Figure 7		1.4	5.0	ns
BW	-3 dB Bandwidth	$R_L = 150 \Omega$, $T_A = 25^{\circ}C$			570	MHz
X _{talk}	Crosstalk Adjacent Non-Adjacent	10 MHz, C_L = 0 pF, R_L = 150 Ω		-47 -80		dB
Off _{ISO}	Off Isolation	10 MHz, C_L = 0 pF, R_L = 150 Ω		-48		dB

6. T_A = $+25^{\circ}$ C, parameters characterized but not tested.

CAPACITANCES (Note 7)

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{IN}	Control Pin Input Capacitance	V _{CC} = 5.0 V		2.0		pF
C _{I/OA}	A Port Input/Output Capacitance	$V_{CC} = \overline{OE} = 5.0 V$		5.0		pF
C _{I/OB}	B Port Input/Output Capacitance	$V_{CC} = \overline{OE} = 5.0 V$		5.0		pF

7. T_A = $+\,25^\circ C,\,f$ = 1 MHz, Capacitance is characterized but not tested.



TYPICAL CHARACTERISTICS



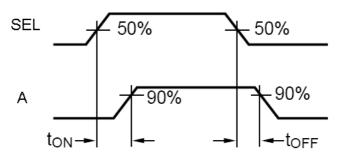


Figure 7. Turn-on and Turn-off Times

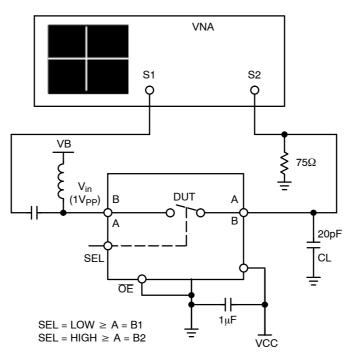
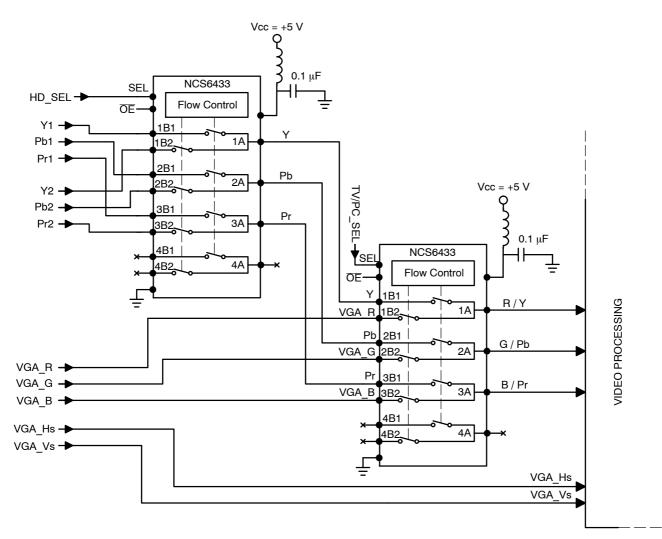


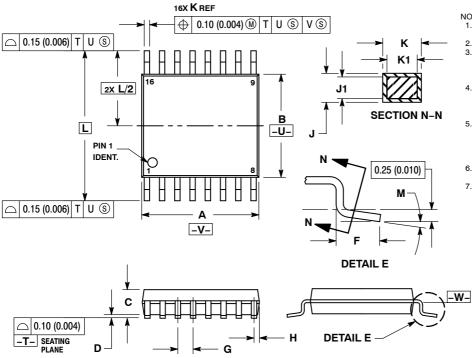
Figure 8. Gain, Crosstalk, Off-Isolation





PACKAGE DIMENSIONS

TSSOP-16 CASE 948F-01 **ISSUE B**

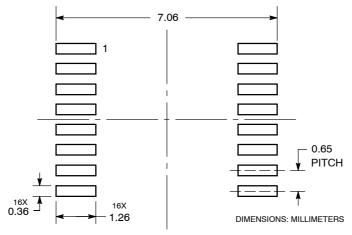


NOTES: 1. DIMENSIONING AND TOLERANCING PER

- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER. 2. З.
- 4.
- CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT 5.
- IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 6.
- DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-. 7.

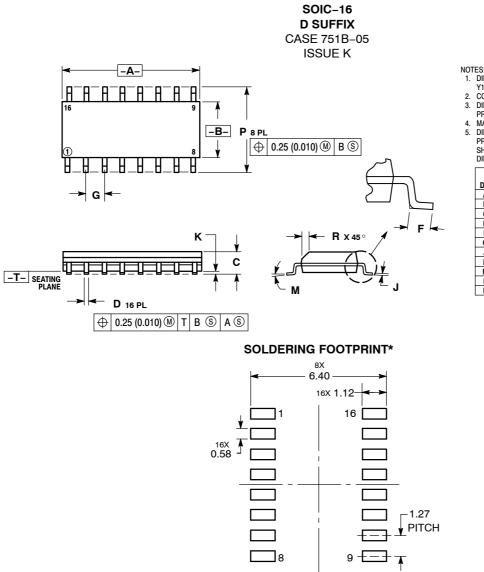
	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
В	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
н	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
ĸ	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40		0.252	
Μ	0 °	8 °	0 °	8 °

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILC does not convey any license under its patent rights or the rights of others. SCILC products are not designed, intended, or authorized for use a components in systems intended for surgical implant into the body, or other applications. intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor P.O. Box 5163, Denver, Colorado 80217 USA Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910 Japan Customer Focus Center Phone: 81-3-5773-3850

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION

MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	1.27 BSC		BSC
J	0.19	0.25	0.008	0.009
Κ	0.10	0.25	0.004	0.009
М	0 °	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019